## 1 General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

PNP complements: BCW68F/G/H

### 2 Features and benefits

High current

AEC-Q101 qualified

## 3 Applications

· General-purpose switching and amplification

### 4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base		-	-	45	V
I <sub>C</sub>	collector current			-	-	800	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-	1	Α
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 1 V; $I_{C}$ = 100 mA; $T_{amb}$ = 25 °C	[1]				
	BCW66F			100	-	250	
	BCW66G			160	-	400	
	BCW66H			250	-	600	

[1] pulsed:  $t_p \le 300 \mu s$ ,  $\delta \le 0.02$ 



## 5 Pinning information

### **Table 2. Pinning**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base		
2	Е	emitter	3	C
3	С	collector		BE sym123

## 6 Ordering information

**Table 3. Ordering information** 

Table of Oracining Information					
Type number	Package				
	Name	Description	Version		
BCW66F	TO-236AB	plastic surface-mounted package; 3 leads	SOT23		
BCW66G					
BCW66H					

## 7 Marking

Table 4. Marking

Table 4. Marking					
Ty	ype number		Marking code		
В	CW66F	[1]	EQ%		
В	CW66G	[1]	ER%		
В	CW66H	[1]	ES%		

<sup>[1] % =</sup> placeholder for manufacturing site code

## 8 Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	50	V
$V_{CEO}$	collector-emitter voltage	open base	-	45	V
$V_{EBO}$	emitter-base voltage	open collector	-	5	V
I <sub>C</sub>	collector current		-	800	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	1	Α
I <sub>B</sub>	base current		-	100	mA

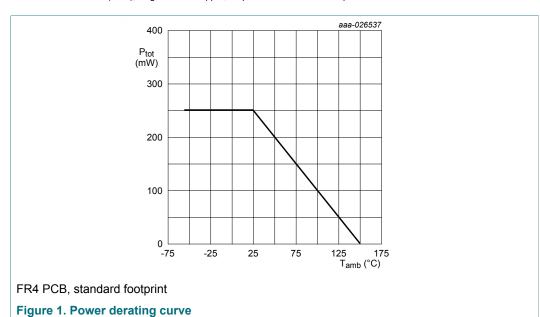
BCW66x\_SER

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Symbol	Parameter	Conditions	Min	Max	Unit
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms	-	200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$ [1]	-	250	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	150	°C
T <sub>stg</sub>	storage temperature		-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB), single-sided chopper, tin-plated and standard footprint.

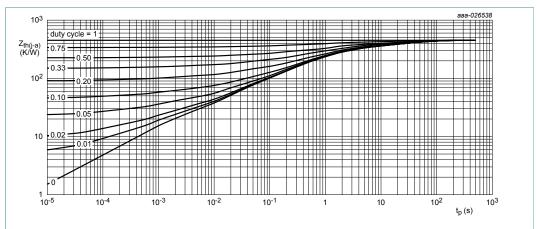


### 9 Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air [1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



FR4 PCB, standard footprint

Figure 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

### 10 Electrical characteristics

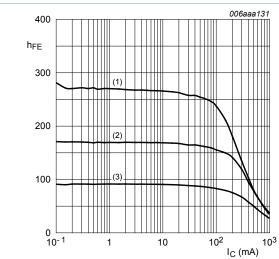
#### Table 7. Electrical characteristics

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base	V <sub>CB</sub> = 40 V; I <sub>E</sub> = 0 A		-	-	20	nA
	cut-off current	$V_{CB}$ = 40 V; $I_{E}$ = 0 A; $T_{j}$ = 150 °C		-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A		-	-	20	nA
h <sub>FE</sub>	DC current gain						<u> </u>
	BCW66F/G/H	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 100 μA		75	-	-	
	BCW66F/G/H	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 1 mA		75	-	-	
	BCW66F/G/H	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 10 mA		75	-	-	
	BCW66F	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 100 mA	[1]	100	-	250	
	BCW66G		[1]	160	-	400	
	BCW66H		[1]	250	-	630	
	BCW66F/G/H	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 500 mA	[1]	40	-	-	
V <sub>CEsat</sub>	collector-emitter	I <sub>C</sub> = 100 mA; I <sub>B</sub> = 10 mA	[1]	-	-	350	mV
	saturation voltage	I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA	[1]	-	-	450	mV
V <sub>BEsat</sub>	base-emitter	I <sub>C</sub> = 100 mA; I <sub>B</sub> = 10 mA	[1]	-	-	1.25	V
	saturation voltage	I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA	[1]	-	-	1.25	V
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; f = 100 MHz		100	-	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = i <sub>e</sub> = 0 A; f = 1 MHz		-	3	-	pF

<sup>[1]</sup> pulsed;  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 

Table 8.



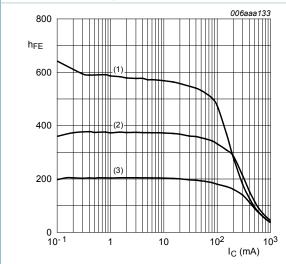
$$V_{CE} = 1 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55$$
 °C

Figure 3. BCW66F: DC current gain as a function of collector current; typical values



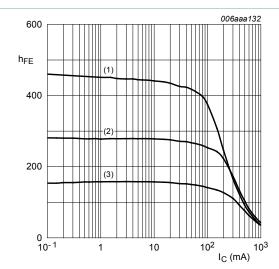
$$V_{CE} = 1 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = -55 °C$$

Figure 5. BCW66H: DC current gain as a function of collector current; typical values

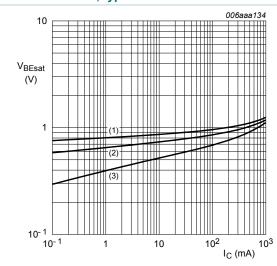


$$V_{CE} = 1 V$$

(2) 
$$_{amb}$$
 = 25  $^{\circ}$ C

(3) 
$$_{amb}$$
 = -55  $^{\circ}$ C

Figure 4. BCW66G: DC current gain as a function of collector current; typical values

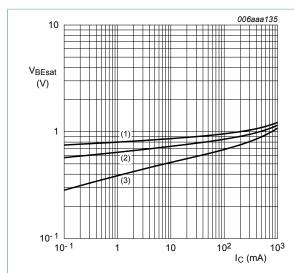


$$I_C/I_B = 10$$

(1) 
$$T_{amb} = -55 \,^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Figure 6. BCW66F: Base-emitter saturation voltage as a function of collector current; typical values

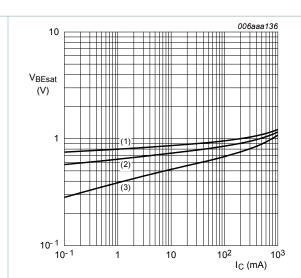


$$I_C/I_B = 10$$

(1) 
$$T_{amb} = -55$$
 °C

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$



$$I_{\rm C}/I_{\rm B} = 10$$

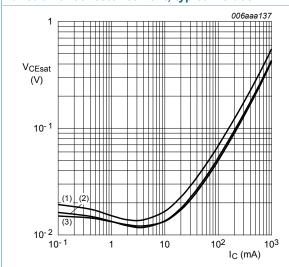
(1) 
$$T_{amb} = -55$$
 °C

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Figure 7. BCW66G: Base-emitter saturation voltage as a function of collector current; typical values

Figure 8. BCW66H: Base-emitter saturation voltage as a function of collector current; typical values



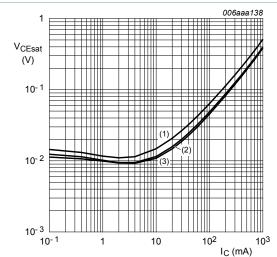
$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55$$
 °C

Figure 9. BCW66F: Collector-emitter saturation voltage as a function of collector current; typical values



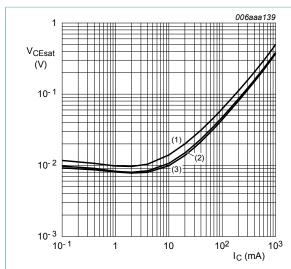
$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Figure 10. BCW66G: Collector-emitter saturation voltage as a function of collector current; typical values



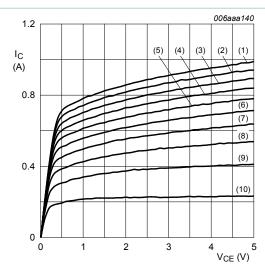
$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb}$$
 = 150 °C

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb}$$
 = -55 °C

Figure 11. BCW66H: Collector-emitter saturation voltage as a function of collector current; typical values



 $T_{amb}$  = 25 °C

(1)  $I_B = 16.0 \text{ mA}$ 

(2)  $I_B = 14.4 \text{ mA}$ 

(3)  $I_B = 12.8 \text{ mA}$ 

(4)  $I_B = 11.2 \text{ mA}$ 

(5)  $I_B = 9.6 \text{ mA}$ (6)  $I_B = 8.0 \text{ mA}$ 

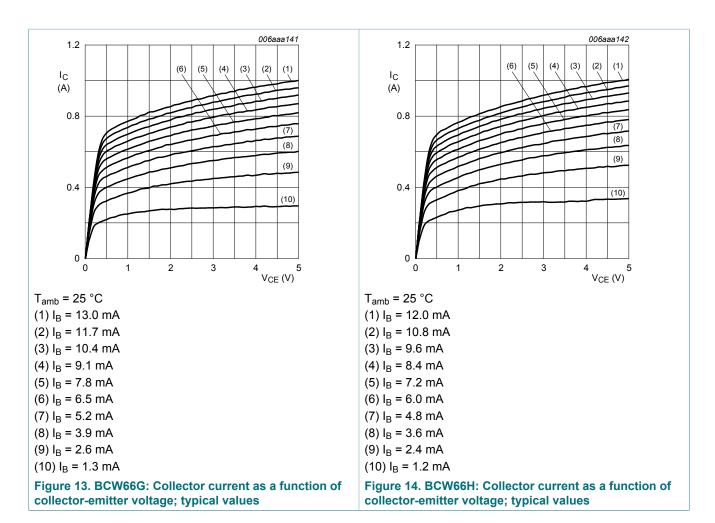
 $(7) I_B = 6.4 \text{ mA}$ 

(8)  $I_B = 4.8 \text{ mA}$ 

(9)  $I_B = 3.2 \text{ mA}$ 

 $(10) I_B = 1.6 mA$ 

Figure 12. BCW66F: Collector current as a function of collector-emitter voltage; typical values



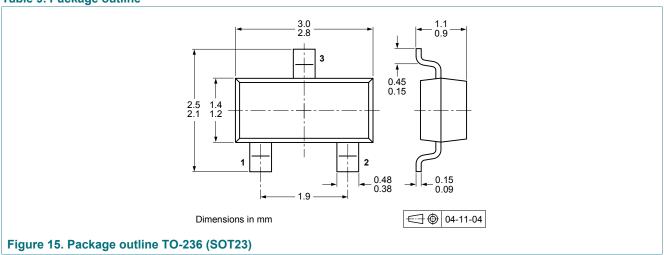
### 11 Test information

### 11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

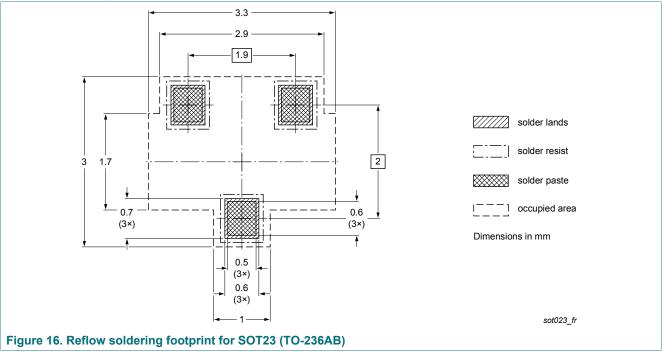
## 12 Package outline

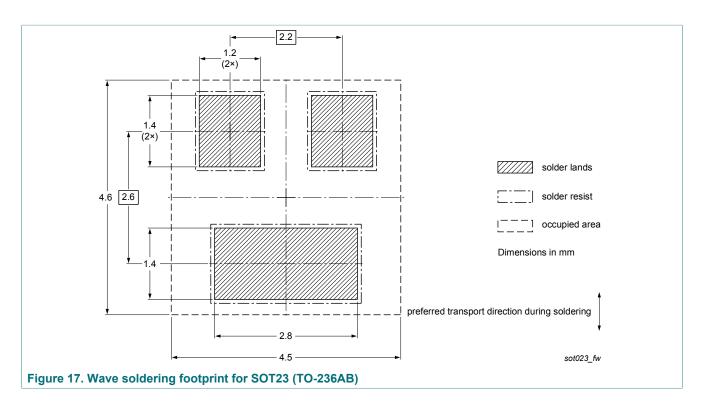
### Table 9. Package outline



## 13 Soldering

### Table 10. Soldering





# 14 Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BCW66x_SER v.1	21 April 2017	Product data sheet	-	-

### 15 Legal information

#### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
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# **BCW66** series

45 V, 800 mA NPN general-purpose transistor

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# **BCW66** series

45 V, 800 mA NPN general-purpose transistor

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